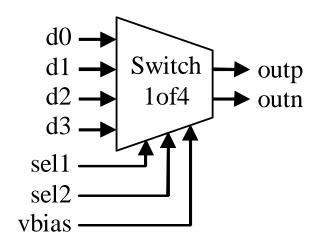
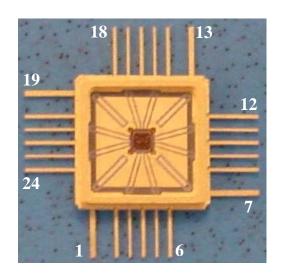


ASNT1122-KMC 32Gb/s 1-of-4 Switch

- High speed broadband Switch of 4 inputs to one output.
- Exhibits low jitter and limited temperature variation over industrial temperature range.
- Ideal for high speed proof-of-concept prototyping.
- CML compliant single ended input data buffers.
- CML compliant differential output data buffer.
- Digital control signals.
- Adjustable duty cycle.
- Single -3.3*V* power supply.
- Low power consumption of <400mW at 32Gbps.
- Fabricated in SiGe for high performance, yield, and reliability.
- Custom CQFP 24-pin package.

DESCRIPTION





Functional Block Diagram

Package View

Rev.: 1, May 2011 1 ASNT1122-KMC



DESCRIPTION

The temperature stable and broadband ASNT1122-KMC SiGe IC is a high isolation selector switch that is intended for use in high-speed measurement / test equipment. The switch routs one of 4 single-ended CML inputs ("d0", "d1", "d2", "d3") to its differential CML output "outp/outn" while effectively blocking the other data inputs with high isolation. Selection of a specific data input is controlled by two digital control signals "sel1" and "sel2" in accordance with Table 1. Duty cycle of the output signal is controlled by external analog voltage "vbias".

Table 1. Switch Controls

sel1	sel2	out
0	0	d0
0	1	d2
1	0	d1
1	1	d3

The part operates from a single -3.3V power supply. Its I/Os support CML logic interface with on chip 50*Ohm* termination.

TERMINAL FUNCTIONS

TERMINAL		TYPE	DESCRIPTION		
NAME	(NO.)	l			
VCC	2,4,6,8,10,12	PS	External ground		
14,1	16,18,20,22,24				
vee	1,13,19	PS	Negative power Supply: -3.3V		
d0p	15	Input	Single-ended CML high-speed data signal		
d1p	17		Single-ended CML high-speed data signal		
d2p	21	Input	Single-ended CML high-speed data signal		
d3p	23		Single-ended CML high-speed data signal		
sel1	3	Input	2.5 V digital control signals		
sel2	5				
outp	11	Output	Differential CML high-speed data signal		
outn	9				
vbias	7	Input	Analog control voltage		



ELECTRICAL CHARACTERISTICS

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS
VEE	-3.1	-3.3	-3.5	V	±6%
VCC		0		V	External ground
IEE		110		mA	_
Power		360		mW	
Junction Temp.	-25	50	125	$^{\circ}C$	
Input Data (d)					
Data rate	DC		32	Gbps	
CM Level		-330		mV	At "vbias" = "vee"
SE Swing	50	300	600	mV	Peak-to-peak
Input Select (sel)					
Frequency	DC		1.0	MHz	
Logic "0" level	vcc-2.5	5	vcc-2.3	V	
Logic "1" level	vcc-0.2	2	vcc	mV	Peak-to-peak
Input Bias (vbias)					
Voltage range	vee		vcc	V	
Output Data (out)					
Data rate	0.0		32	Gbps	
CM Level	Vcc-0.3	Vcc-0.2	2 Vcc-0.1	V	
SE Swing	380	400	420	mV	Peak-to-peak
Rise/Fall Times	14	15	16	ps	20%-80%
Additive Jitter			<2	ps	Peak-to-peak

PACKAGE INFORMATION

The chip is packaged in a custom 24-pin CQFP package. The package's mechanical information is available on the company's <u>website</u>.